# NSN 5961-01-013-5238

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

## **Overall Length:**

Between 1.553 inches and 1.573 inches

# **Overall Diameter:**

1.050 inches

# **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 7.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown

voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 4.00 amperes source cutoff current

## Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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